Triple Buffer with Open Drain Outputs

The NL37WZ07 is a high performance triple buffer with open drain outputs operating from a 1.65 V to 5.5 V supply.

The internal circuit is composed of multiple stages, including an open drain output which provides the capability to set output switching level. This allows the NL37WZ07 to be used to interface 5 V circuits to circuits of any voltage between $V_{\rm CC}$ and 7 V using an external resistor and power supply.

Features

- Extremely High Speed: t_{PD} 2.5 ns (typical) at $V_{CC} = 5 \text{ V}$
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Overvoltage Tolerant Inputs
- LVTTL Compatible Interface Capability with 5 V TTL Logic with V_{CC} = 3 V
- LVCMOS Compatible
- 24 mA Output Sink Capability @ 3.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

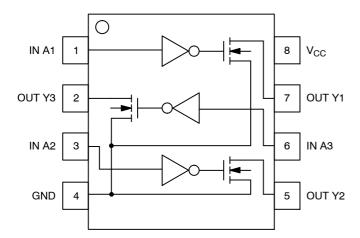


Figure 1. Pinout

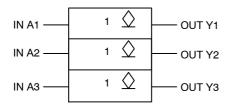


Figure 2. Logic Symbol



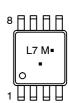
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MARKING DIAGRAM



US8 US SUFFIX CASE 493



L7 = Device Code M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

PIN ASSIGNMENT

| Pin | Function | |
|-----|-----------------|--|
| 1 | IN A1 | |
| 2 | OUT Y3 | |
| 3 | IN A2 | |
| 4 | GND | |
| 5 | OUT Y2 | |
| 6 | IN A3 | |
| 7 | OUT Y1 | |
| 8 | V _{CC} | |
| | | |

FUNCTION TABLE

| A Input | Y Output |
|---------|----------|
| L | L |
| Н | Z |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

| Symbol | Parameter | Value | Units |
|-------------------|--|------------------------|-------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | V |
| VI | DC Input Voltage | -0.5 to +7.0 | V |
| Vo | DC Output Voltage | -0.5 to +7.0 | V |
| lık | DC Input Diode Current VI < GND | -50 | mA |
| I _{OK} | DC Output Diode Current V _O < GND | -50 | mA |
| I _O | DC Output Sink Current | ±50 | mA |
| I _{CC} | DC Supply Current per Supply Pin | ±100 | mA |
| I _{GND} | DC Ground Current per Ground Pin | ±100 | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| T_J | Junction Temperature under Bias | +150 | °C |
| $\theta_{\sf JA}$ | Thermal Resistance (Note 1) | 250 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | 250 | mW |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | > 2000 > 150 N/A | V |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Units |
|-----------------|---|-------------|---------------|-------|
| V _{CC} | Supply Voltage Operating Data Retention Only | 1.65 1.5 | 5.5 5.5 | V |
| VI | Input Voltage (Note 5) | 0 | 5.5 | V |
| Vo | Output Voltage (HIGH or LOW State) | 0 | 5.5 | V |
| T _A | Operating Free-Air Temperature | -55 | +125 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | 0 0 0 | 20 10 5 | ns/V |

^{5.} Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | Т | T _A = 25°C | | -55°C ≤ T _A ≤ 125°C | | |
|------------------|---|--|----------------------------|---|-----------------------|---|---|---|-------|
| Symbol | Parameter | Condition | (V) | Min | Тур | Max | Min | Max | Units |
| V _{IH} | High-Level Input Voltage | | 1.65 to 1.95 2.3 to 5.5 | 0.75 V _{CC} 0.7 V _{CC} | | | 0.75 V _{CC} 0.7 V _{CC} | | ٧ |
| V _{IL} | Low-Level Input Voltage | | 1.65 to 1.95 2.3 to 5.5 | | | 0.25 V _{CC} 0.3 V _{CC} | | 0.25 V _{CC} 0.3 V _{CC} | ٧ |
| I _{LKG} | Z-State Output Leakage Current | $V_{IN} = V_{IL}$ $V_{OUT} = V_{CC}$ or GND | 1.65 to 5.5 | | | ±5.0 | | ±10.0 | μΑ |
| V _{OL} | Low-Level Output | I _{OL} = 100 μA | 1.65 to 5.5 | | 0.0 | 0.1 | | 0.1 | V |
| | Voltage V _{IN} = V _{IH} or V _{IL} | I _{OL} = 4 mA | 1.65 | | 0.08 | 0.24 | | 0.24 | |
| | | I _{OL} = 8 mA | 2.3 | | 0.20 | 0.3 | | 0.3 | |
| | | I _{OL} = 12 mA | 2.7 | | 0.22 | 0.4 | | 0.4 | |
| | | I _{OL} = 16 mA | 3.0 | | 0.28 | 0.4 | | 0.4 | |
| | | I _{OL} = 24 mA | 3.0 | | 0.38 | 0.55 | | 0.55 | |
| | | I _{OL} = 32 mA | 4.5 | | 0.42 | 0.55 | | 0.55 | |
| I _{IN} | Input Leakage Current | V _{IN} = 5.5 V or GND | 0 to 5.5 | | | ±0.1 | | ±1.0 | μΑ |
| I _{OFF} | Power Off Leakage Current | V _{IN} = 5.5 V or V _{OUT} = 5.5 V | 0 | | | 1 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{IN} = 5.5 V or GND | 5.5 | | | 1 | | 10 | μΑ |

AC ELECTRICAL CHARACTERISTICS t_R = t_F = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

| | | | | 1 | T _A = 25°C | | -55°C ≤ T _A ≤ 125°C | | |
|------------------|-------------------|--|---------------------|-----|-----------------------|-----|--------------------------------|-----|-------|
| Symbol | Parameter | Condition | V _{CC} (V) | Min | Тур | Max | Min | Max | Units |
| t _{PZL} | Propagation Delay | $R_L = R_1 = 500 \Omega$, $C_L = 50 pF$ | 1.8 ± 0.15 | | | 7.8 | | 7.8 | ns |
| | (Figure 3 and 4) | $R_L = R_1 = 500 \Omega, C_L = 50 pF$ | 2.5 ± 0.2 | 1.2 | 3.7 | 5.8 | 1.2 | 6.4 | |
| | | $R_L = R_1 = 500 \Omega, C_L = 50 pF$ | 3.3 ± 0.3 | 0.8 | 2.9 | 4.4 | 0.8 | 4.8 | |
| | | $R_L = R_1 = 500 \Omega, C_L = 50 pF$ | 5.0 ± 0.5 | 0.5 | 2.3 | 3.5 | 0.5 | 3.9 | |
| t _{PLZ} | Propagation Delay | $R_L = R_1 = 500 \Omega, C_L = 50 pF$ | 1.8 ± 0.15 | | | 7.8 | | 7.8 | ns |
| (Figure 3 and 4) | | $R_L = R_1 = 500 \Omega, C_L = 50 pF$ | 2.5 ± 0.2 | 1.2 | 2.8 | 5.8 | 1.2 | 6.4 | |
| | | $R_L = R_1 = 500 \Omega$, $C_L = 50 pF$ | 3.3 ± 0.3 | 0.8 | 2.1 | 4.4 | 0.8 | 4.8 | |
| | | $R_L = R_1 = 500 \Omega$, $C_L = 50 pF$ | 5.0 ± 0.5 | 0.5 | 1.4 | 3.5 | 0.5 | 3.9 | |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Units |
|------------------|--|--|---------|-------|
| C _{IN} | Input Capacitance | V_{CC} = 5.5 V, V_I = 0 V or V_{CC} | 2.5 | pF |
| C _{OUT} | Output Capacitance | V_{CC} = 5.5 V, V_I = 0 V or V_{CC} | 4.0 | pF |
| C _{PD} | Power Dissipation Capacitance (Note 6) | 10 MHz, V _{CC} = 5.5 V, V _I = 0 V or V _{CC} | 4.0 | pF |

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

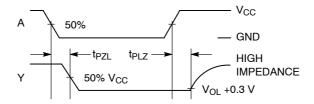
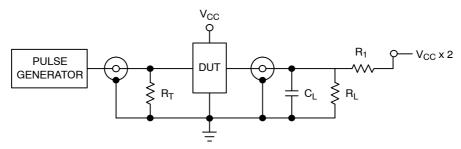


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

DEVICE ORDERING INFORMATION

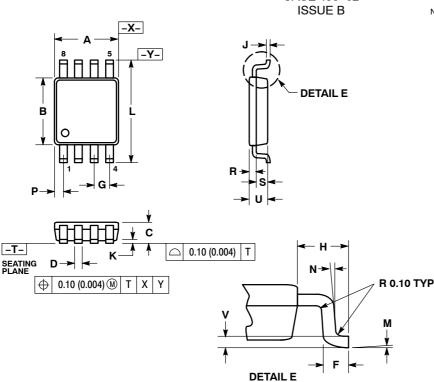
| Device Order Number | Package | Shipping [†] |
|---------------------|------------------|-----------------------|
| NL37WZ07USG | US8 (Pb-Free) | 3000 / Tape & Reel |
| NLV37WZ07USG* | US8 (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

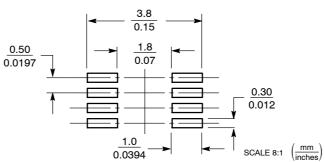
US8 CASE 493-02



- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM (0.0055") PER SIDE.
- DIMENSION "B" DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSION. INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM.
- (300–800 "). ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 (0.0002 ").

| | MILLIN | METERS | INCHES | | |
|-----|----------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 1.90 | 2.10 | 0.075 | 0.083 | |
| В | 2.20 | 2.40 | 0.087 | 0.094 | |
| С | 0.60 | 0.90 | 0.024 | 0.035 | |
| D | 0.17 | 0.25 | 0.007 | 0.010 | |
| F | 0.20 | 0.35 | 0.008 | 0.014 | |
| G | 0.50 | BSC | 0.020 | BSC | |
| Н | 0.40 | REF | 0.016 | REF | |
| J | 0.10 | 0.18 | 0.004 | 0.007 | |
| K | 0.00 | 0.10 | 0.000 | 0.004 | |
| L | 3.00 | 3.20 | 0.118 | 0.126 | |
| М | 0 ° | 6 ° | 0 ° | 6° | |
| N | 5 ° | 10 ° | 5 ° | 10 ° | |
| P | 0.23 | 0.34 | 0.010 | 0.013 | |
| R | 0.23 | 0.33 | 0.009 | 0.013 | |
| S | 0.37 | 0.47 | 0.015 | 0.019 | |
| U | 0.60 | 0.80 | 0.024 | 0.031 | |
| V | 0.12 BSC | | 0.005 BSC | | |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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